December 2011



FGP15N60UNDF 600V, 15A **Short Circuit Rated IGBT**

Features

- · Short circuit rated 10us
- High current capability
- · High input impedance
- Fast switching
- RoHS compliant



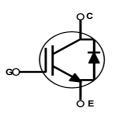
Applications

- · Home appliance inverter-driven appplication - Air Condtioner, Washing Machine, Refrigerator, Dish Washer
- Industrial Inverter Sewing Machine, CNC

General Description

Using advanced NPT IGBT Technology, Fairchild's the NPT IGBTs offer the optimum performance for low power inverterdriven applications where low-losses and short circuit ruggedness feature are essential.





Absolute Maximum Ratings

Symbol	Description		Ratings	Units
V _{CES}	Collector to Emitter Voltage		600	V
V _{GES}	Gate to Emitter Voltage		± 20	V
I _C	Collector Current	@ T _C = 25 ^o C	30	A
	Collector Current	@ T _C = 100°C	15	A
I _{CM (1)}	Pulsed Collector Current	@ T _C = 25 ^o C	45	А
I _F	Diode Forward Current	@ T _C = 25°C	15	А
P _D	Maximum Power Dissipation	@ T _C = 25 ^o C	178	W
	Maximum Power Dissipation	@ T _C = 100°C	71	W
TJ	Operating Junction Temperature		-55 to +150	°C
T _{stg}	Storage Temperature Range		-55 to +150	°C

Notes: 1: Repetitive test , Pulse width=100usec , Duty=0.2, V_{GE} =13.5V

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Units
$R_{\theta JC}(IGBT)$	Thermal Resistance, Junction to Case		0.7	°C/W
$R_{\theta JC}(Diode)$	Thermal Resistance, Junction to Case		2.3	°C/W
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient (PCB Mount)(2)		62.5	°C/W

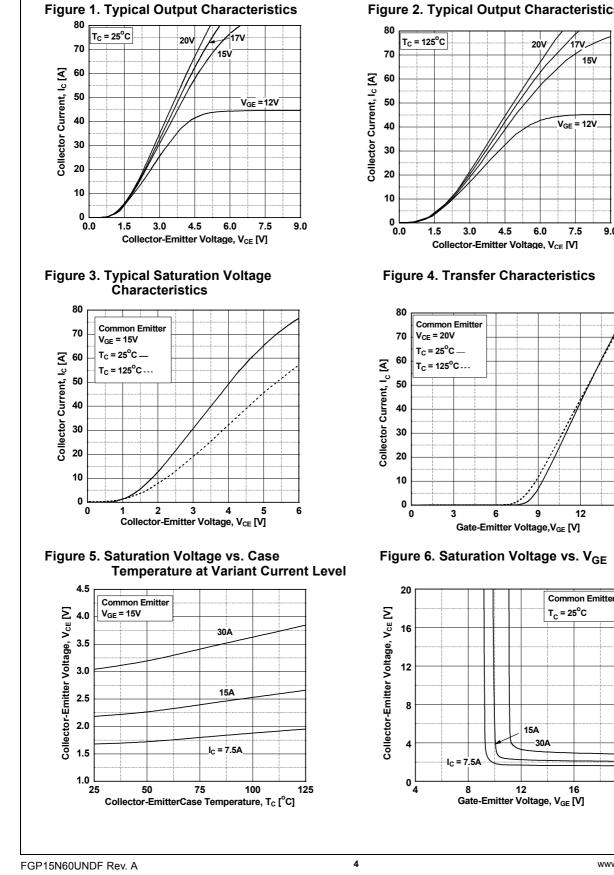
		Package	Packaging Package Type		Qty per Tube		Max Qty per Box	
		TO220	Tube	50	Dea		-	
Electric		enteriotice of th						
Symbol		Parameter		c = 25°C unless otherwise noted	Min.	Тур.	Max.	Units
Off Charac	toristics							
BV _{CES}		to Emitter Breakdown Vol	tage Vor = 0	V, I _C = 250μA	600	-	_	V
I _{CES}		Cut-Off Current		$V_{CES}, V_{GE} = 0V$	-	_	1	mA
I _{GES}		age Current		$V_{\text{GES}}, V_{\text{CE}} = 0V$	_	-	±10	μA
			·GE ·	GES, CE CI				pu i
On Charac			1 - 45	$-\lambda = \lambda$		6.0	0.5	V
V _{GE(th)}	G-E Inres	shold Voltage	_	mA, $V_{CE} = V_{GE}$	5.5	6.8	8.5	V
V _{CE(sat)}	Collector to Emitter Saturation Voltage		000	$A, V_{GE} = 15V$	-	2.2	2.7	V
CE(sat)			$T_{\rm C} = 157$ $T_{\rm C} = 12$	A, V _{GE} = 15V, 5°C	-	2.7	-	V
Dynamic C	haracteris	tics	÷					
C _{ies}	Input Cap				-	619	-	pF
C _{oes}		apacitance		0V, V _{GE} = 0V,	-	80	-	pF
C _{res}		Fransfer Capacitance	f = 1MH	Z	-	24	-	pF
	Charaotari	ation			-	<u> </u>	<u>I</u>	
Switching t _{d(on)}	1	Delay Time			-	9.3	-	ns
t _r	Rise Time				-	9.8	_	ns
		Delay Time		00)/ 1 - 154	_	54.8	-	ns
t _{d(off)} t _f	Fall Time			00V, I _C = 15A,)Ω, V _{GE} = 15V,	_	9.9	12.8	ns
E _{on}		Switching Loss	Inductiv	e Load, T _C = 25°C	-	0.37	-	mJ
E _{off}		Switching Loss			_	0.067	-	mJ
Ε _{ts}		ching Loss			-	0.44	-	mJ
t _{d(on)}		Delay Time			_	8.9	_	ns
t _r	Rise Time	,			-	9.9	-	ns
t _{d(off)}		Delay Time	$V_{ab} = A$.00V, I _C = 15A,	-	56.6	-	ns
-d(011) t _f	Fall Time	,	R _G = 10	Ω, V _{GE} = 15V,	-	13.2	-	ns
E _{on}	Turn-On S	Switching Loss	Inductiv	e Load, T _C = 125°C	-	0.54	-	mJ
E _{off}		Switching Loss			-	0.11	-	mJ
E _{ts}		ching Loss			-	0.65	-	mJ
T _{sc}		cuit Withstand Time	V _{CC} = 3 R _G = 10 T _C = 15	00Ω, V _{GE} = 15V,	10	-	-	μs

Electrical Characteristics of the IGBT $T_{C} = 25^{\circ}C$ unless otherwise noted

Qg	Total Gate Charge		-	43	-	nC
Q _{ge}	Gate to Emitter Charge	V _{CE} = 400V, I _C = 15A, V _{GE} = 15V	-	6	-	nC
Q _{gc}	Gate to Collector Charge		-	26	-	nC

Electrical Characteristics of the Diode $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions		Min.	Тур.	Max	Units
V _{FM} D	Diode Forward Voltage	I _F = 15A	T _C = 25°C	-	1.6	2.2	V
			T _C = 125°C	-	1.5	-]]]
t	Diode Reverse Recovery Time		T _C = 25°C	-	82.4		ns
۲rr			T _C = 125°C	-	142	-	
Q _{rr}	Diode Reverse Recovery Charge		T _C = 25°C	-	213	-	nC
~ []			T _C = 125°C	-	541	-	



Typical Performance Characteristics

Figure 2. Typical Output Characteristics

15V

9.0

15

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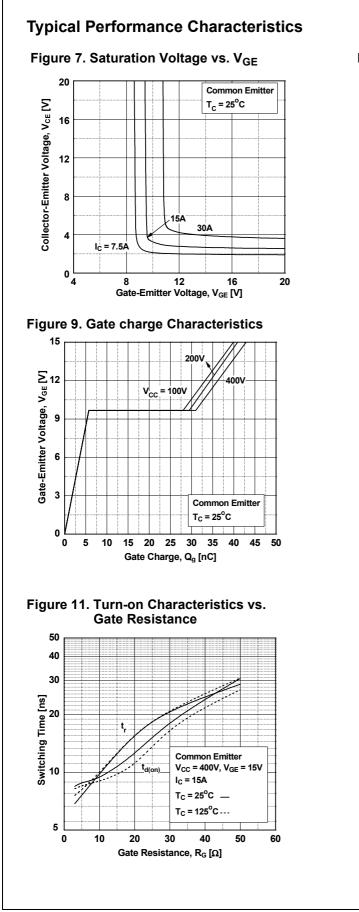
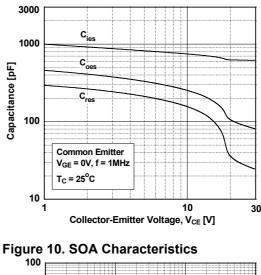
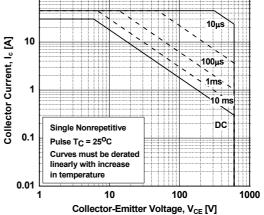
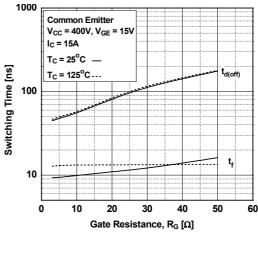


Figure 8. Capacitance Characteristics









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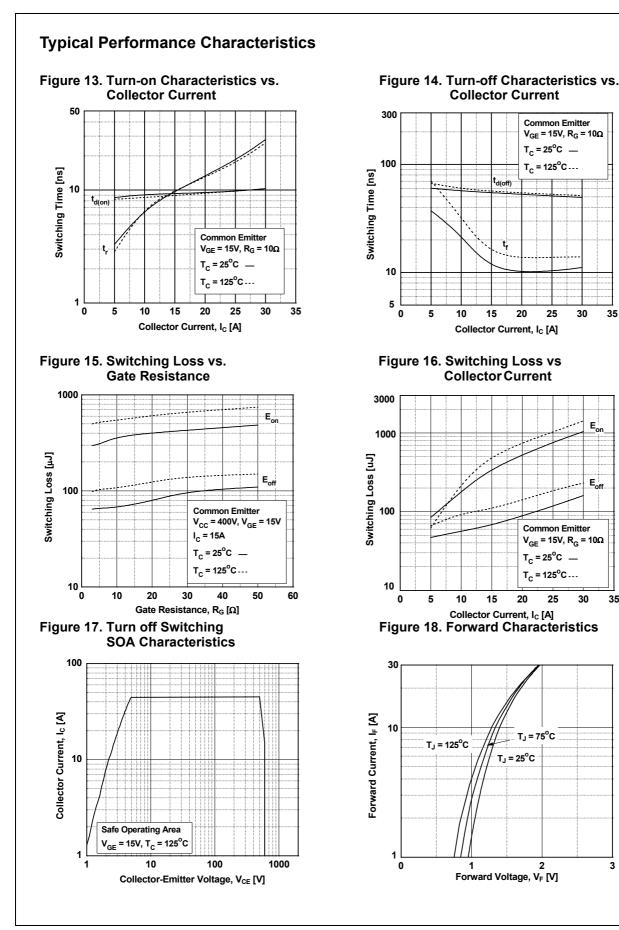
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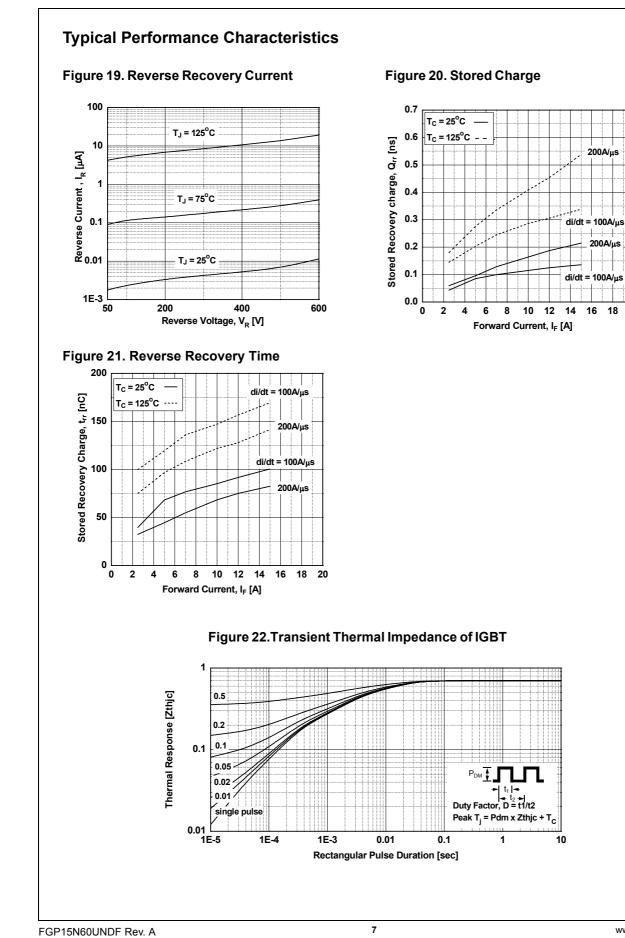
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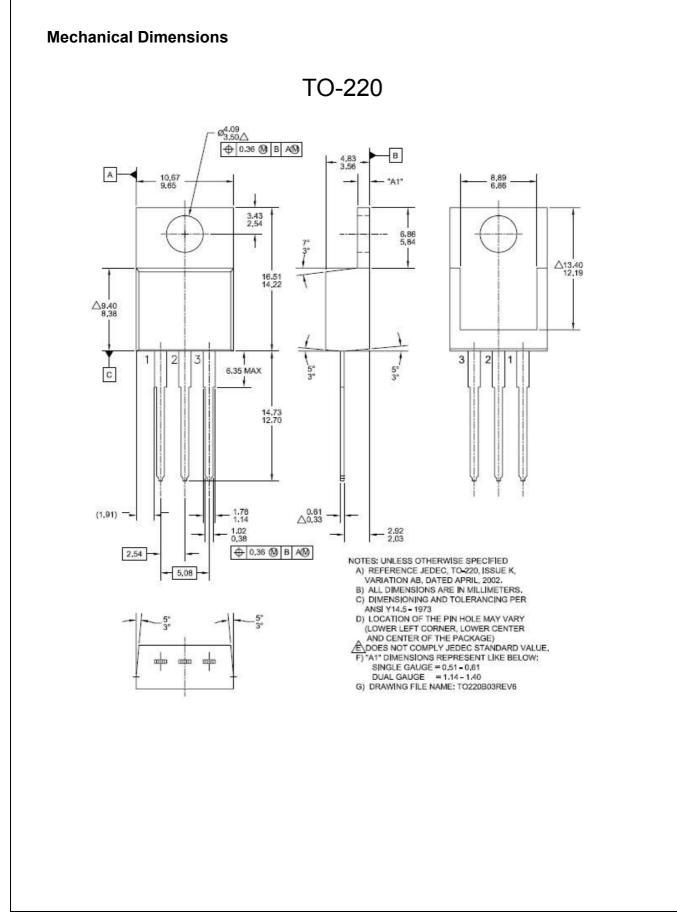
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200A/µs

200A/µs

16 18 20







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